

EAST Search History

S11 2	4	nanolithography near3 (probe).ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 13:40
S11 3	4	"6703272"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 13:40
S11 4	3	"6171952"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 13:40
S11 5	34	"5754571"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/05/22 09:26
S11 6	22	"4530600"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/05/22 09:31
S11 7	17484	semiconductor with (Scan\$2 scanning)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/05/22 09:43
S11 8	502	(amorphous with semiconductor) with (Scan\$2 scanning)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/05/22 09:42
S11 9	7322	semiconductor with (Scan\$2 scanning) with laser	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/05/22 09:43
S12 0	757	semiconductor with (Scan\$2 scanning) with laser with speed\$3	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/05/22 09:43
S12 1	472	semiconductor with (Scan\$2 scanning) with laser with speed\$3 with beam	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/05/22 09:43

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S40	503	(amorphous with substrate) with (scan\$2 scanning)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/09/13 08:58
S41	261	S40 and (amorphous with substrate scan\$2 scanning) with laser	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 14:04
S42	241	S41 and (amorphous with substrate scan\$2 scanning laser) with beam	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/07 14:38
S44	119	S42 and (amorphous with substrate scan\$2 scanning laser beam) with speed	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/07 14:45
S45	119	S42 and (amorphous with substrate scan\$2 scanning laser beam) with (speed speeding)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 10:56
S46	56	S45 and (amorphous with substrate scan\$2 scanning laser beam) with (spot)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 10:59
S47	46	S46 and (amorphous with substrate scan\$2 scanning laser beam) with (light)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/07 14:47
S48	42	S46 and (scan\$2 scanning laser beam light) with shape	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 10:24
S49	126368	"7" and (scan\$2 scanning laser beam light) with shape	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 10:24
S50	503	(amorphous with substrate) with (scan\$2 scanning)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 14:02

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S51	261	S50 and (amorphous with substrate scan\$2 scanning) with laser	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 10:56
S52	241	S51 and (amorphous with substrate scan\$2 scanning laser) with beam	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 10:56
S53	119	S52 and (amorphous with substrate scan\$2 scanning laser beam) with (speed speeding)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 16:15
S54	56	S53 and (amorphous with substrate scan\$2 scanning laser beam) with (spot)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 10:59
S55	89	S53 and (amorphous with substrate scan\$2 scanning laser beam) with (pulse)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 10:59
S56	50	S55 and (amorphous with substrate scan\$2 scanning laser beam) with (intensity)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 11:02
S57	3	S55 and (amorphous with substrate scan\$2 scanning laser beam) with (intensity with nm)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 11:00
S58	0	S55 and (amorphous with substrate scan\$2 scanning laser beam) with (cross\$3 near\$3 hat)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 11:02
S59	40	S55 and (amorphous with substrate scan\$2 scanning laser beam) with (rectangular)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 16:13
S60	3	S55 and (amorphous with substrate scan\$2 scanning laser beam) with (hat)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 11:04

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S61	65	S55 and (amorphous with substrate scan\$2 scanning laser beam) with (rectangular linear ellipse elliptical ellipsoid ellipsoidal oval)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 16:14
S62	13	S61 and (adjust adjusted adjust\$3 chang\$3) with (speed speeding)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/08 16:15
S63	14590	((amorphous (cryatalline crystalization cryatallizing cryatalinity crystal) with substrate)) with (laser)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/09 09:55
S64	7038	(amorphous cryatalline crystalization cryatallizing cryatalinity crystal substrate) with (laser with (scanning scan\$3))	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/09 09:35
S65	5921	S64 and (beam) with (laser scanning scan\$3)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/09 09:35
S66	2193	S65 and (spot sharpe) with (beam laser scanning scan\$3)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/09 09:36
S67	964	S66 and (irradiating irradiat\$2) with (beam laser scanning scan\$3)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/09 09:37
S68	453	S67 and (irradiating irradiat\$2 beam laser scanning scan\$3) with (oscillation oscillator oscillat\$3)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/09 09:39
S69	354	S68 and (irradiating irradiat\$2 beam laser scanning scan\$3) with (linear rectangular ellipse elliptical ellipsoidal)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/09 09:40

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S70	287	S69 and (irradiating irradiat\$2 beam laser scanning scan\$3 linear rectangular ellipse elliptical ellipsoidal) with speed	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/09 09:41
S71	106	S69 and (adjusted adjust\$3 control\$2 controlling change\$ changing) with speed	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/09 11:53
S72	14659	((amorphous (cryatalline crystalization crystallizing crystalinity crystal) with substrate)) with (laser)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/09 09:55
S73	1	10/671539	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/09 12:10
S74	1	(laser near3 annealling) with amorphous	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/09 12:11
S75	2877	(laser with anneal\$4) with amorphous	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/22 09:59
S76	863	(laser with anneal\$4) with (amorphous with substrate)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/22 09:59
S77	451	S76 and (laser anneal\$4 amorphous substrate) with (scanning scan\$2)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/22 10:01
S78	361	S77 and irradiat\$5	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/22 10:07
S79	284	S78 and grain	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/22 10:04

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S80	213	S78 and oscillat\$4	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/22 10:06
S81	182	S80 and mirror	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/22 10:05
S84	158	S81 and speed\$4	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/22 10:06
S85	105	S84 and continuous	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/22 10:06
S86	105	S85 and (irradiation irradiated)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/22 10:07
S87	102	S86 and light	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/22 18:02
S88	1	10/671539	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/22 12:41
S89	9	"6531723"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 09:11
S90	7	"6635506"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 09:13
S91	3	"6667245"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 09:38

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S92	34	"6428859"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 09:54
S93	1	"6857449"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 09:57
S94	1	"6821898"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 09:54
S95	0	2005/106078	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 09:57
S96	1	"2005106078"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 10:01
S97	4	microfluidic with device.ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 10:02
S98	557	microfluidic with device.ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 10:30
S99	2289	electro adj optical adj device.ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 10:31
S10 0	1191	electro adj optical adj device with method.ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 10:38
S10 1	936	lithographic adj apparatus. ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 10:42

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S10 2	19	"5426355"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 10:42
S10 3	91	rotation with driving with (apparatus method).ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 10:48
S10 4	1	10/908249	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 10:57
S10 5	247	(irradiation near3 (system apparatus)) with beam.ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 13:10
S10 6	8	MICROTOOL.ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 13:15
S10 7	33	dry adj air near3 (apparatus system).ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 13:19
S10 8	0	cryogenic adj batcher adj banyan adj network\$.ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 13:21
S10 9	2	cryogenic with network\$.ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 13:21
S11 0	1	batcher adj banyan adj network\$.ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 13:26
S11 1	0	nanolithography near3 (system apparatus).ti.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/23 13:27

EAST Search History

S12 2	97	semiconductor with (Scan\$2 scanning) with laser with speed\$3 with beam with surface	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/05/22 09:46
S12 3	153	(semiconductor and (Scan\$2 scanning) and laser and speed\$3 and beam and surface).clm.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/05/22 09:56
S12 4	70	(semiconductor and (Scan\$2 scanning) and laser and speed\$3 and beam and surface and spot).clm.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/05/22 09:56
S12 5	258	(semiconductor and (Scan\$2 scanning) and laser and speed\$3 and beam and surfaceand spot and amorphous).clm.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/05/22 09:59
S12 6	3	(semiconductor and (Scan\$2 scanning) and laser and speed\$3 and beam and surface and spot and amorphous).clm.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/05/22 09:59
S12 7	3	(semiconductor and (Scan\$2 scanning) and laser and speed\$3 and beam and surface and spot and amorphous).clm.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 14:05
S12 8	1876	438/463,487,535,662,940.ccls.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:04
S12 9	3657	438/166,308,378,487-488,795.ccls.	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:04
S13 0	4872	S128 or S129	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:05
S13 1	2626	S130 and laser	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:06

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S13 2	1196	S130 and laser near3 light	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:06
S13 3	395	S131 and (laser with speed)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:55
S13 4	321	S133 and amorphous	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:21
S13 5	33262	((amorphous with (layer film)) wiht substrate) with (scan\$2 scanning)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:14
S13 6	476	((amorphous with (layer film)) with substrate) with (scan\$2 scanning)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:15
S13 7	2949	((amorphous with (layer film)) with substrate) with (laser)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:15
S13 8	830	S137 and (scan scaning scan\$3) with (laser)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:16
S13 9	587	S137 and (scan scaning scan\$3 laser) with-speed\$3	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:17
S14 0	694	S138 and (scan scaning scan\$3 laser speed\$3) with surface	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 13:17
S14 1	1	"6169292".PN.	USPAT; USOCR	OR	OFF	2006/06/29 13:19
S14 2	1	"5534716".PN.	USPAT; USOCR	OR	OFF	2006/06/29 13:19
S14 3	1	"5177578".PN.	USPAT; USOCR	OR	OFF	2006/06/29 13:19

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S14 4	1	"4630089".PN.	USPAT; USOCR	OR	OFF	2006/06/29 13:19
S14 5	1	"5962870".PN.	USPAT; USOCR	OR	OFF	2006/06/29 13:20
S14 6	1	"5142344".PN.	USPAT; USOCR	OR	OFF	2006/06/29 13:20
S14 7	1	"6297862".PN.	USPAT; USOCR	OR	OFF	2006/06/29 13:56
S14 8	1	"5648662".PN.	USPAT; USOCR	OR	OFF	2006/06/29 13:56
S14 9	1	"5244819".PN.	USPAT; USOCR	OR	OFF	2006/06/29 13:57
S15 0	1	"4608095".PN.	USPAT; USOCR	OR	OFF	2006/06/29 13:57
S15 1	1	"5102819".PN.	USPAT; USOCR	OR	OFF	2006/06/29 13:57
S15 2	81	("5244819").URPN.	USPAT	OR	OFF	2006/06/29 13:58
S15 3	476	((amorphous with (layer film)) with substrate) with (scan\$2 scanning)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 14:03
S15 4	2572	(semiconductor and (Scan\$2 scanning) and laser and speed\$3 and beam and surface and spot and amorphous)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/06/29 14:05
S15 5	1	10/671539	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/09/13 08:59
S15 6	1	10/219815	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/09/13 09:20
S15 7	1	"20020096680"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/09/13 09:42

EAST Search History

S15 8	37	laser with amorphous with position with chang\$3	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/09/13 09:43
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